





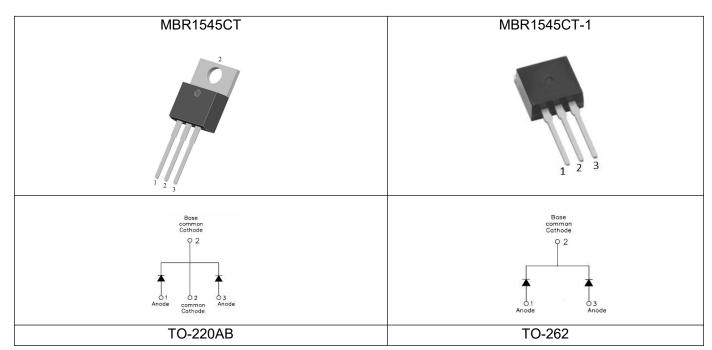
MBR1545CT/MBR1545CT-1 SCHOTTKY RECTIFIER

Features

- 150 °C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Terminals finish: Tin Lead-free plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection



Maximum Ratings@Tc=25°C unless otherwise specified

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	45	V
Average Rectified Forward Current	I _{F (AV)}	Tc=130°C, In DC	7.5(Per Leg) 15(Per Device)	А
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse	150	А

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Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop	V_{F1}	@ 15A, Pulse, T _J = 25 °C	0.70	0.84	V
(Per Leg)*	V _{F2}	@ 15A, Pulse, T _J = 125 °C	0.67	0.72	V
Reverse Current (Per Leg)*	I _{R1}	$@V_R = \text{rated } V_R$ $T_J = 25 ^{\circ}\text{C}$	0.02	1.0	mA
	I _{R2}	$@V_R = \text{rated } V_R$ $T_J = 125 ^{\circ}\text{C}$	12	15	mA
Junction Capacitance(Per Leg)	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	305	400	pF
Typical Series Inductance (Per Leg)	Ls	Measured lead to lead 5 mm from package body	8.0	-	nΗ
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

 $^{^{\}star}\,$ Pulse width < 300 $\mu s,\,$ duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case(Per Leg)	R ₀ JC	DC operation	1.5	°C/W
Case Style	TO-220AB TO-262			







Ratings and Characteristics Curves

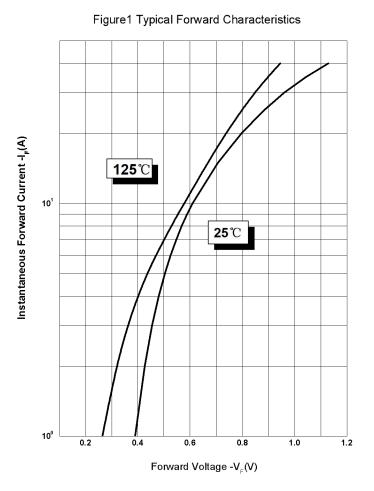
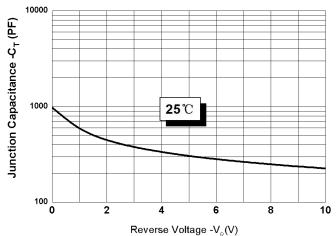


Figure 3 Typical Junction Capacitance



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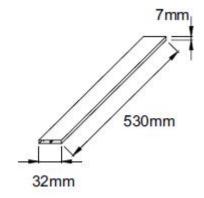




Tube Specification

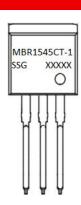
Device	Package	Weight	Shipping
MBR1545CT	TO-220AB	1.8g	50pcs / tube
MBR1545CT-1	TO-262	1.85g	50pcs / tube

Tube Specification(TO-220AB/TO-262)



Marking Diagram





Where XXXXX is YYWWL

 MBR
 = Device Type

 15
 = Forward Current (15A)

 45
 = Reverse Voltage (45V)

 CT -1
 = Configuration

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

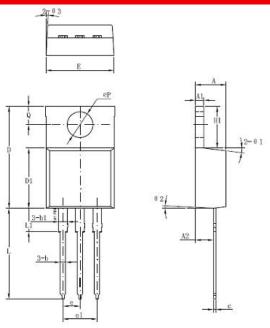
Cautions: Molding resin Epoxy resin UL:94V-0





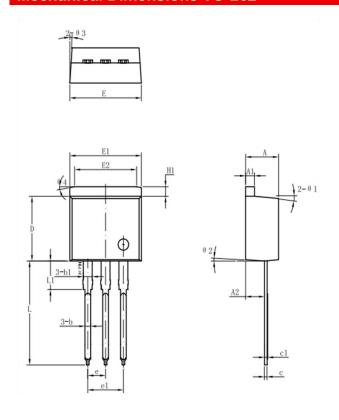


Mechanical Dimensions TO-220AB



Symbol	Dimensions in millimeters		
	Min	Typical	Max
Α	3.56	-	4.83
A1	0.51	-	1.4
A2	2.03	-	2.92
b	0.38	-	1.02
b1	1.14	-	1.78
С	0.31	-	0.61
D	14.22	-	16.51
D1	8.38	-	9.42
E	9.65	-	10.67
е	-	2.54	-
e1	-	5.08	-
H1	5.84	-	6.86
L	12.7	-	14.73
L1	-	-	6.35
ФР	-	3.56	-
Q	2.54	-	3.43

Mechanical Dimensions TO-262



Symbol	Millimeters			
	Min.	Typical	Max.	
Α	4.55	4.70	4.85	
A1	1.17	1.27	1.37	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1		1.27		
С	0.36	0.38	0.61	
D	8.55	8.70	8.85	
E	10.01	10.16	10.31	
E1	9.88	10.08	10.28	
е		2.54		
e1		5.08		
H1	1.17	1.27	1.37	
L	13.00	13.86	14.08	
L1		3.8		
	0	-	8°	
Θ1		5°		
Θ2		4°		
Θ3		4°		
Θ4		10°		

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